EGBU3504 THRU EGBU3506





GLASS PASSIVATED SUPER FAST SINGLE-PHASE BRIDGE RECTIFIER

REVERSE VOLTAGE: 400 to 600 VOLTS FORWARD CURRENT: 35.0 AMPERE

FEATURES

· Glass passivated chip junction

· Reliable low cost construction utilizing molded plastic technique

- · Ideal for printed circuit board
- · Low forward voltage drop
- · Low reverse leakage current
- · High surge current capability

MECHANICAL DATA

Case: Molded plastic, GBJ

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202,

method 208 guaranteed Mounting position: Any

Mounting Torque: 8.17 inches-lbs max.

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GBJ

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098 (2.5)
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Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	EGBJ3504	EGBJ3506	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	400	600	Volts
Maximum RMS Voltage	V _{RMS}	280	420	Volts
Maximum DC Blocking Voltage	V _{DC}	400	600	Volts
Maximum Average Forward Rectified Current with Heatsink at T_C =90 $^{\circ}$ C	I _(AV)	35		Amp
Peak Forward Surge Current,				
8.3ms single half-sine-wave	I_{FSM}	I _{FSM} 250		Amp
superimposed on rated load (JEDEC method)				
Maximum Forward Voltage Drop per Element at 17.5A DC and 25 ℃	V_{F}	1.5	2.0	Volts
Maximum Reverse Current at T _A =25℃	10.0		0.0	uAmp
at Rated DC Blocking Voltage T _A =125℃	I_R	500		
Typical Junction Capacitance (Note 1)	C_{J}	60		pF
Maximum Reverse Recovery Time (Note 2)	T_{RR}	50		nS
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	0.8		°C/W
Operating and Storage Temperature Range	T _J , Tstg	-55 to +150		ဗ

NOTES

- 1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2- Reverse Recovery Test Conditions: I_F =.5A, I_R =1A, I_{RR} =.25A.
- 3- Thermal Resistance fromn Junction to Case with Device Mounted on 300mm x 300mm x 1.6mmCu Plate Heatsink.





RATINGS AND CHARACTERISTIC CURVES

Fig.1 Forward Current Derating Curve

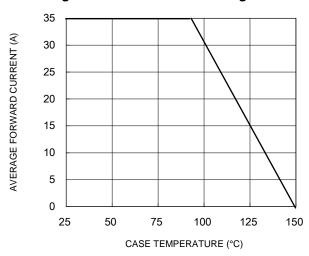


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

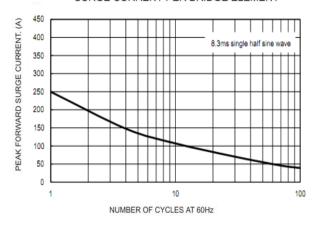


FIG.3- TYPICAL REVERSE CHARACTERISTICS

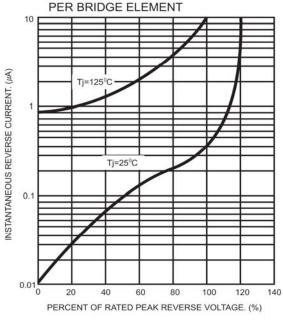


FIG.4- TYPICAL FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

